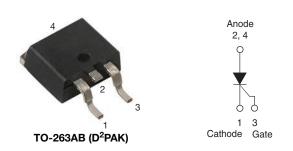


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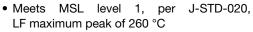
Vishay Semiconductors

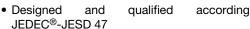
Thyristor Surface Mount, Phase Control SCR, 8 A

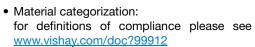


PRODUCT SUMMARY					
Package	TO-263AB (D ² PAK)				
Diode variation	Single SCR				
I _{T(AV)}	8 A				
V _{DRM} /V _{RRM}	800 V				
V_{TM}	1.2 V				
I _{GT}	15 mA				
T_J	-40 to +125 °C				

FEATURES











ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- Input rectification and crow-bar (soft start)
- Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-12TTS08S-M3 High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS								
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C, common heatsink of 1 °C/W	13.5	17	А					

MAJOR RATINGS AND CHARACTERISTICS								
PARAMETER	TEST CONDITIONS	VALUES	UNITS					
I _{T(AV)}	Sinusoidal waveform	8	٨					
I _{T(RMS)}		12.5	А					
V _{RRM} /V _{DRM}		800	V					
I _{TSM}		110	Α					
V _T	8 A, T _J = 25 °C	1.2	V					
dV/dt		150	V/µs					
dl/dt		100	A/μs					
TJ	Range	-40 to +125	°C					

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA
VS-12TTS08S-M3	800	800	1.0



ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL		TEST CONDITIONS	VALUES	UNITS			
Maximum average on-state current	I _{T(AV)}	T 100 °C	T 100 °C 100° conduction half size ways					
Maximum RMS on-state current	I _{T(RMS)}	1 _C = 106 C,	180° conduction, half sine wave	12.5				
Maximum peak one-cycle	1	10 ms sine pu	ılse, rated V _{RRM} applied, T _J = 125 °C	95	Α			
non-repetitive surge current	I _{TSM}	10 ms sine pu	ılse, no voltage reapplied, T _J = 125 °C	110				
Maximum I ² t for fusing	l ² t	10 ms sine pu	ulse, rated V _{RRM} applied, T _J = 125 °C	45	A ² s			
waxiinum i-t ior iusing	1-1	10 ms sine pu	ılse, no voltage reapplied, T _J = 125 °C	64	A-5			
Maximum $I^2\sqrt{t}$ for fusing	I ² √t	t = 0.1 ms to	640	$A^2\sqrt{s}$				
Maximum on-state voltage drop	V_{TM}	8 A, T _J = 25 °	8 A, T _J = 25 °C		V			
On-state slope resistance	r _t	T _{.1} = 125 °C	T 105 %		$m\Omega$			
Threshold voltage	V _{T(TO)}	1J = 125 C		0.87	V			
Maximum reverse and direct leakage current	1 //	T _J = 25 °C	V - Potod V A	0.05				
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	V_R = Rated V_{RRM}/V_{DRM}	1.0				
Typical holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, I_J = 25 °C		30	mA			
Maximum latching current	IL	Anode supply	50					
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max.},$	T _J = T _J max., linear to 80 %, V _{DRM} = R _g - k = Open					
Maximum rate of rise of turned-on current	dl/dt			100	A/µs			

TRIGGERING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak gate power	P _{GM}		8.0	W			
Maximum average gate power	P _{G(AV)}		2.0	VV			
Maximum peak positive gate current	+ I _{GM}		1.5	Α			
Maximum peak negative gate voltage	- V _{GM}		10	V			
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	20	mA			
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	15				
		Anode supply = 6 V, resistive load, T _J = 125 °C	10				
		Anode supply = 6 V, resistive load, T _J = - 65 °C	1.2				
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	1	1 V			
		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7	V			
Maximum DC gate voltage not to trigger V _{GD}		T. = 125 °C V Potod value	0.2				
Maximum DC gate current not to trigger I _{GD}		T _J = 125 °C, V _{DRM} = Rated value	0.1	mA			

SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8				
Typical reverse recovery time	t _{rr}	T 105 °C	3	μs			
Typical turn-off time	t _q	T _J = 125 °C	100				



THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +125	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.5			
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W		
Typical thermal resistance case to heatsink	· Ru		Mounting surface, smooth and greased	0.5			
Approximate weight				2	g		
Approximate weight	Approximate weight			0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque —	maximum			12 (10)	(lbf \cdot in)		
Marking device			Case style D ² PAK (SMD-220)	12TT:	S08S		

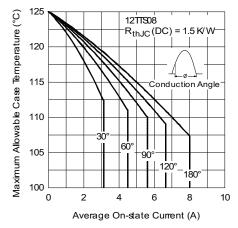


Fig. 1 - Current Rating Characteristics

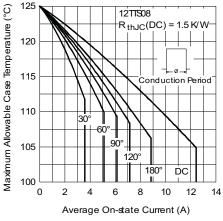


Fig. 2 - Current Rating Characteristics

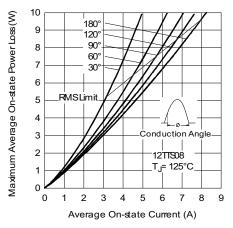


Fig. 3 - On-State Power Loss Characteristics

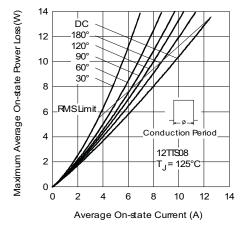


Fig. 4 - On-State Power Loss Characteristics

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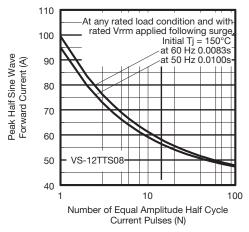


Fig. 5 - Maximum Non-Repetitive Surge Current

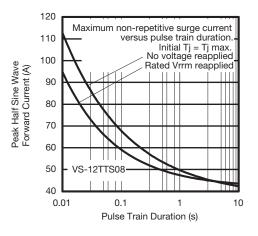


Fig. 6 - Maximum Non-Repetitive Surge Current

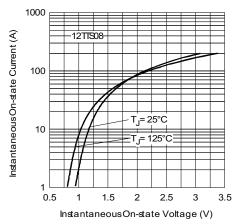


Fig. 7 - On-State Voltage Drop Characteristics

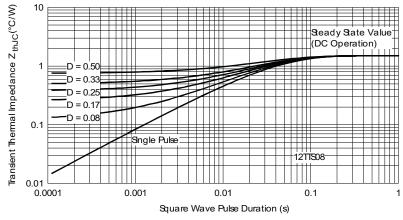
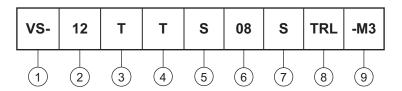


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (12.5 A)

3 - Circuit configuration:

T = Single thyristor

4 - Package:

 $T = D^2PAK$

5 - Type of silicon:

S = Standard recovery rectifier

6 - Voltage rating (08 = 800 V)

- S = Surface mountable

8 - • None = Tube

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

9 - -M3 = Halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-12TTS08S-M3	50	1000	Antistatic plastic tubes					
VS-12TTS08STRR-M3	800	800	13" diameter reel					
VS-12TTS08STRL-M3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95046				
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?95032				



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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